



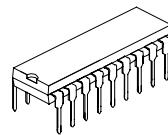
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SC9102C/D

TONE / PULSE DIALER WITH REDIAL FUNCTION

DESCRIPTION

The SC9102C/D are Tone/Pulse switchable dialer which are fabricated in COMS technology with wide operating voltage for both tone and pulse mode, and consumes very low memory retention current in on hook state.

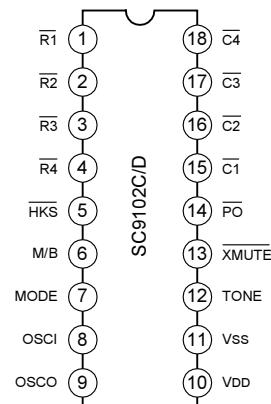


DIP-18

FEATURES

- *Tone/Pulse switchable dialer
- *One 32-digit last number redial memory
- *Pulse-to-tone (P→T) is provided for PBX operation
- *Flash key is available
- *Minimum tone duration is 100ms
- *Minimum intertone pause is 106ms
- *Uses 3.579549MHz crystal or ceramic resonator
- *Redial Pause time (0ms)
- *Mixed dialing
- *Power on reset circuit is provided
- *Many options can be selected
- Mode (10PPS; 20PPS; Tone)
- M/B ratio (40:60;33:66)
- Pause time (3.6ms)
- *Flash function (RESET)
- (P→T) pause time (3.6ms)
- Flash time (600/100ms)
- Flash pause time (0ms)
- *Packaged in 18-pin plastic DIP

PIN CONFIGURATIONS



ORDERING INFORMATION

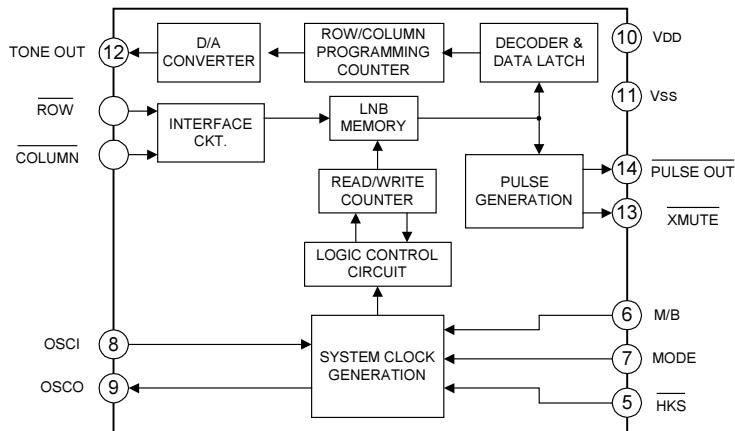
SC9102C	DIP-18 Packaged
SC9102D	DIP-18 Packaged



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BLOCK DIAGRAM



KEYBOARD ASSIGNMENT

	$\overline{C1}$	$\overline{C2}$	$\overline{C3}$	$\overline{C4}$
$\overline{R1}$	1	2	3	$P \rightarrow T$
$\overline{R2}$	4	5	6	F
$\overline{R3}$	7	8	9	P
$\overline{R4}$	*P	0	#/RD	RD

Note: 1) $P \rightarrow T$: Execute $P \rightarrow T$ function.

2) P: Pause key.

3) F: Flash key

4) RD: Redial key

5) *P: In Tone mode, execute * function; In pulse mode, execute pause function

6) #/RD: In Tone mode, execute # function; In pulse mode, execute redial function

DIALING SIGNAL OPTION

M/B	Pulse Rate	M/B Ratio	Flash Time	
			SC9102D	SC9102C
VSS	10PPS	40:60	600ms	100ms
VDD	10PPS	33:66	100ms	600ms
Open	20PPS	33:66	600ms	600ms

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ABSOLUTE MAXIMUM RATINGS

(Tamb=25°C, All voltage referenced to Vss, unless otherwise specified)

Characteristic	Symbol	Value	Unit
Power Supply Voltage	VDD	6.0	V
Input Voltage	VIN	-0.3~VDD+0.3	V
Power Dissipation	PD	500	mW
Operating Temperature	Topr	-25~+70	°C
Storage Temperature	Tstg	-55~+150	°C

ELECTRICAL CHARACTERISTICS

(Tamb=25°C , VDD=2.5V, fosc=3.579545MHz, unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating Voltage	VDD	Tone/Pulse	2.0		5.5	V
		Memory retention	1.0		5.5	
Operating Current	IOP	Tone		0.6	2	mA
		Pulse, OFF-HOOK, Keypad entry, no load		0.2	0.6	
Standby Current	IS	ON-HOOK, No keypad entry, no load VDD=1.0V		0.1	5	µA
Memory Retention Current	Imr			0.1	0.1	µA
Control Pin Input Low Voltage	Vil		VSS		0.3VDD	V
Control Pin Input High Voltage	Vih		0.7VDD		VDD	
XMUTE Pin Leakage Current	Imth	V _{XMUTE} =12.0V			1	µA
XMUTE Pin Sink Current	Imtl	V _{XMUTE} =0.5V	1			mA
HKS Pin Input Current	Ihks	V _{hks} =2.5V			0.1	µA
Keyboard Drive Current	Ikbd	Vn=0V (note1)	4	10	30	µA
Scanning Pin Sink Current	Ikbs	Vn=2.5 (note1)	200	400		
Key-in Debounce Time	tDB			20		ms
Pulse Mode						
Pulse Output Pin Leakage Current	Ipoh	V _{po} =12V	--	--	1.0	µA
Pulse Output Pin Sink Current	Ipol	V _{po} =0.5V	1. 0	3.0	--	mA
Pulse Rate	fpr		--	10	--	pps
			--	20	--	
Make/Break Ratio	t _M : t _B		--	40:60	--	%
			--	33:66	--	

(to be continued)

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Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Pre-digit Pause (Pulse rate=10pps)	t_{PDP}	M/B ratio=40:60	--	40	--	ms	
		M/B ratio=33:66	--	33	--		
Pre-digit Pause (Pulse rate=20pps)	t_{PDP}	M/B ratio=40:60	--	20	--	ms	
		M/B ratio =33:66	--	16.5	--		
Inter-digit Pause	t_{IDP}	Pulse rate=10pps	--	800	--	ms	
		Pulse rate=20pps	--	600	--		
Tone Mode							
Tone Output Pin	DC Level	Vdc	VDD=2.0V~5.5V	0.45VDD	0.55VDD	0.7VDD	V
	Sink Current	I_t	Vdtmpf=0.5V	0.15	--	--	mA
	AC level	Vdtmpf	Row group, $R_L=10K\Omega$	120	150	180	mVrms
	Load Resistor	R1	Dist.<=-23dB	10	--	--	KΩ
DTMF Signal	Pre-emphasis	twist	VDD=2.0~5.5 V	1	2	3	dB
	Distortion(note 2)	Dist.	$R_L=10K\Omega$	--	-30	-23	dB
Minimum tone duration Time	t_{TD}		Auto redial	--	100	--	ms
Minimum Intertone Pause Time	t_{TTP}		Auto redial	--	106	--	ms

Note: 1. Vn: Input voltage of any keyboard scanning pin (Row group, Column group)

$$2. \text{ Distortion (dB)} = 20\log\left(\left[V_1^2 + V_2^2 + V_3^2 + \dots + V_n^2\right]^{1/2}\right) / \left[\left(V_L^2 + V_H^2\right)^{1/2}\right]$$

V_L, V_H : Row group and Column group signal

V_1, V_2, \dots, V_n : Harmonic signal (BW = 300Hz~3500Hz)

ACTUAL FREQUENCY OUTPUT (fosc=3.579545MHz)

Keyboard Scanning Pin		Standard(Hz)	Output	Deviation(%)
R1	f1	697	699	+0.28
R2	f2	770	766	-0.52
R3	f3	852	848	-0.47
R4	f4	941	948	+0.74
C1	f5	1209	1216	+0.57
C2	f6	1336	1332	-0.30
C3	f7	1477	1472	-0.34

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Rev: 2.0 2001-11-02



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PIN DESCRIPTION

Pin No.	Pin Name	Description
15	$\overline{C1}$	*Provides keyboard scanning. * HKS pin is LOW, the column group stays in "HIGH" and row group stays in "LOW" state.
16	$\overline{C2}$	*The keypad is compatible with the standard dual contact matrix keyboard (as figure 1b), the inexpensive single contact keyboard (as figure 1a), and electronic input (as figure 1c). *When HKS is "LOW", a valid key entry is defined by related Row & Column connection or by electronic input. *Activation of two or more keys will result in no response, except for single key. *To avoid keyboard-bouncing error, this chip provides built-in debounce circuit. (The debounce time = 20ms)
17	$\overline{C3}$	
18	$\overline{C4}$	
1	$\overline{R1}$	Figure1a: Single contact form keyboard configuration
2	$\overline{R2}$	Figure1b: Dual contact form keyboard configuration
3	$\overline{R3}$	
4	$\overline{R4}$	Figure1c: Electronic signal input keyboard configuration
8	OSCI	*Oscillator input & output pins. *The 3.579545MHz oscillator is formed by a built-in inverter inside of this chip and by connecting a 3.579545MHz crystal or a ceramic resonator across the OSCI and OSCO pins. (built-in feedback resistor and capacitor)
9	OSCO	*When HKS is "LOW", a valid key-in may turn on this oscillator and generates a 3.579545 MHz clock.

(to be continued)

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(continued)

Pin No.	Pin Name	Description		
13	<u>XMUTE</u>	<p>*Mute output pins. *NMOS open drain output structure. *The output is in "LOW" state during dialing sequence (both Pulse and Tone mode) otherwise this pin is "high-impedance". *Long (continue) Mute.</p>		
11	VSS	*Negative power supply pin.		
10	VDD	*Positive power supply pin.		
5	<u>HKS</u>	<p>*Hook switch input pin. *When the handset is in ON-HOOK state, this pin must be pulled "high" in order to disable the dialing operation and decrease the power consumption. *When in OFF-HOOK state, the <u>HKS</u> pin must be pulled "low" state for all function operation.</p>		
14	<u>PO</u>	<p>*Pulse output signal pin. *NMOS open drain output structure. *The output is "LOW" during pulse dialing and Flash operation, otherwise this output is "floating".</p>		
12	TONE	<p>*Dual Tone Multi-frequency output pin. *In TONE mode, when an entry of digit key (include *, # key), this pin will send out a corresponding DTMF signal. *The TONE pin provides minimum tone duration and minimum intertone pause time to support rapid key-in. If key-in time is less than 100ms, DTMF signal will last for 100ms; otherwise the tone duration will last as long as the key is pressed.</p>		
7	MODE	<p>*Mode selection pin. *Three-state input structure. *This pin can select the three modes shown on the right.</p>	MODE	Dialing mode
			VDD	Pulse mode
			Open	Pulse mode
			Vss	Tone mode
6	M/B	*M/B ration selection pin. (The function seeing the Dialing signal option table)		

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KEYBOARD OPERATION

Symbol definitions:

- a) \uparrow : OFF-HOOK or enable Hand Free function.
- b) \downarrow : ON-HOOK or disable Hand Free function.
- c) $\overline{\uparrow}$: Input level from low to high.
- d) $\overline{\downarrow}$: Input level from high to low.
- e) D₁~D_n : Digit key: 1, 2, 3, 4, 5, 6, 7, 8, 9, 0, *, #, (C₁~C_n is same as D₁~D_n).
- f) D_{p1}~D_{pn} : Pulse digit: 1, 2, 3, 4, 5, 6, 7, 8, 9, 0, *, #, (C_{p1}~C_{pn} is same as D_{p1}~D_{pn}).
- g) D_{t1}~D_{tn} : Tone digit: 1, 2, 3, 4, 5, 6, 7, 8, 9, 0, *, #, (C_{t1}~C_{tn} is same as D_{t1}~D_{tn}).
- h) t_F : Flash time.
- i) t_P : Pause time.
- j) t_{PT} : Pulse to Tone wait time.
- k) t_{FP} : Pause time for flash.
- l) t_{RP} : Pause time for redial.
- m) LNB : Last number redial buffer.

A) Normal Dialing

1. Digit Dialing

- Procedure : \uparrow D₁, D₂..., D_n \downarrow
- Dial out : D_{t1}, D_{t2}..., D_{tn} (in Tone mode)
- Dial out : D_{p1}, D_{p2}..., D_{pn} (in Pulse mode)
- LNB : D₁, D₂..., D_n

2. Dialing with flash key

- Procedure : \uparrow F, D₁, D₂..., D_n \downarrow
- Dial out : t_F, t_{FP}, D_{t1}, D_{t2}..., D_{tn} (in Tone mode)
- Dial out : t_F, t_{FP}, D_{p1}, D_{p2}, ..., D_{pn} (in Pulse mode)
- LNB : D₁, D₂..., D_n

3. Dialing with P→T key

- Procedure : \uparrow D₁, D₂ ..., P→T, ..., D_n \downarrow
- Dial out : D_{p1}, D_{p2}, ..., t_{PT}, ..., D_{pn} (in Pulse mode)
- LNB : D₁, D₂ ..., P→T, ..., D_n

Note: If key in digit over maximum digit stored in LNB, then RD is inhibit even after on/off hook.

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B) Mixed dialing

Procedure	:	$\uparrow D1, D2\dots, P \rightarrow T, D9, D10 \dots, Dn \downarrow$
Dial out	:	$Dp1, Dp2, \dots, t_{PT}, Dt9, Dt10 \dots, Dtn$
LNB	:	$D1, D2\dots, P \rightarrow T, D9, D10 \dots, Dn$

C) Redial

LNB	:	$D1, D2\dots, Dn$
Procedure	:	$\uparrow RD \downarrow$
Dial out	:	$t_{RP}, Dt1, Dt2\dots, Dtn$ (in Tone mode)
Dial out	:	$t_{RP}, Dp1, Dp2, \dots, Dpn$ (in Pulse mode)

Note: If key in digit over maximum digit stored in LNB, then RD is inhibit.

D) Pause Function

Procedure	:	$\uparrow D1, D2\dots, Dn, P, C1 \dots, Cn \downarrow$
Dial out	:	$Dt1, Dt2, \dots, Dtn, t_P, Ct1 \dots, Ctn$ (in Tone mode)
Dial out	:	$Dp1, Dp2, \dots, Dpn, t_P, Cp1 \dots, Cpn$ (in Pulse mode)
LNB	:	$D1, D2\dots, Dn, P, C1, C2 \dots, Cn$

E) Flash Function

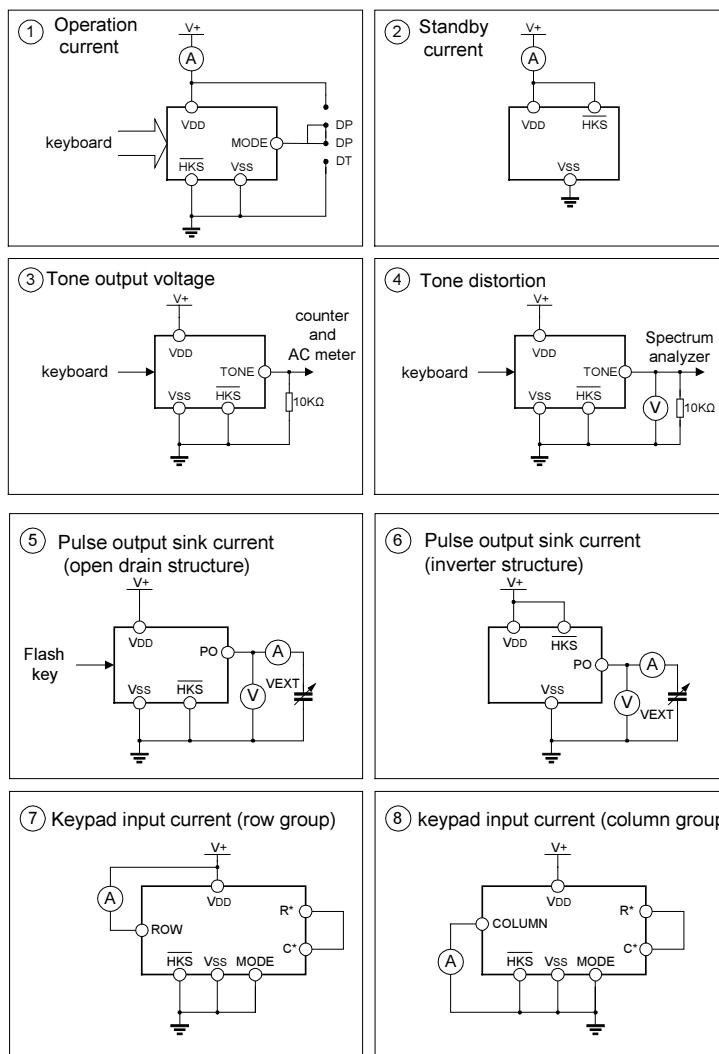
Procedure	:	$\uparrow D1, D2\dots, Dn, F, C1 \dots, Cn \downarrow$
Dial out	:	$Dt1, Dt2, \dots, Dtn, t_F, t_{FP}, Ct1 \dots, Ctn$ (in Tone mode)
Dial out	:	$Dp1, Dp2, \dots, Dpn, t_F, t_{FP}, Cp1 \dots, Cpn$ (in Pulse mode)
LNB	:	$C1, C2 \dots, Cn$



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TEST CIRCUIT



Note: 1. Dist. (dB)= $20\log \{[V_1^2+V_2^2+V_3^2+\dots V_n^2]^{1/2}\}/[(V_L^2+V_H^2)^{1/2}\}$

a. V₁...V_n are extraneous frequencies (ie, inter modulation and harmonic), components in the 500Hz to 3400Hz band.

b. V_L, V_H are the individual frequency components of DTMF signal.

c. Whether keyboard is pushed refer to the TONE mode time diagram.

2. Sink current I_{sink}=I/(1-Duty Cycle), I is the net DC current measured from ampere meter.

3. R*, C* mean other column and row.

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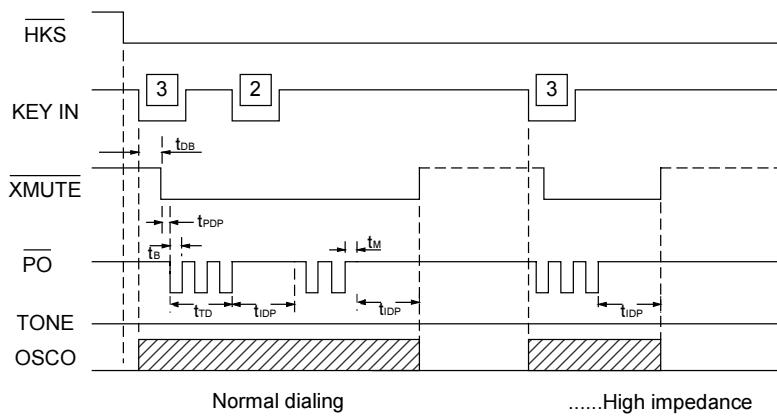
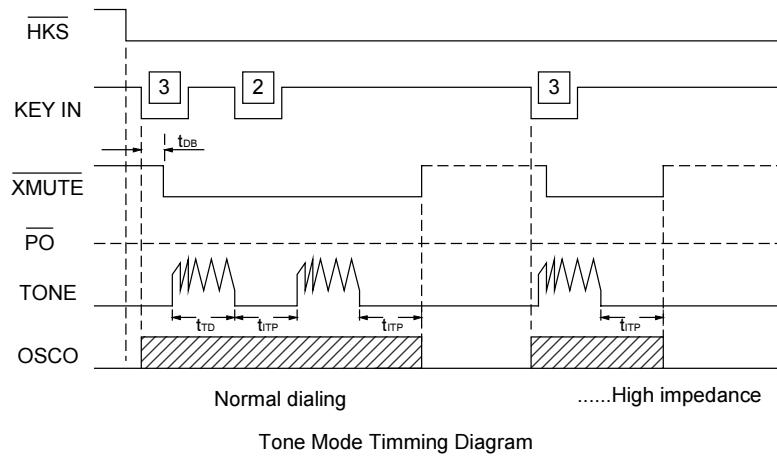
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TIMING DIAGRAMS



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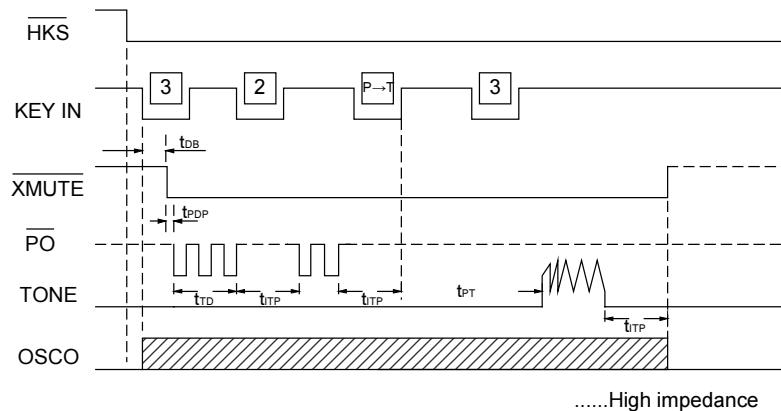
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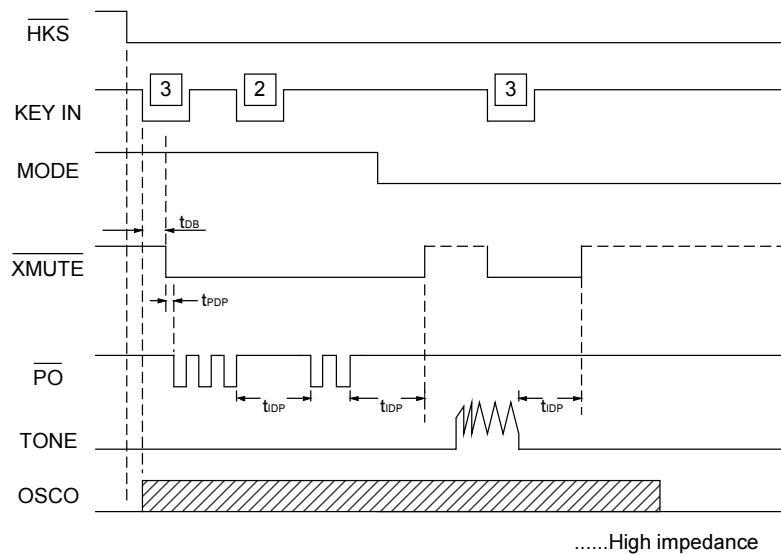
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TIMING DIAGRAMS (continued)



Timing Waveform for mixed dialing Operation
(by */T key entry)



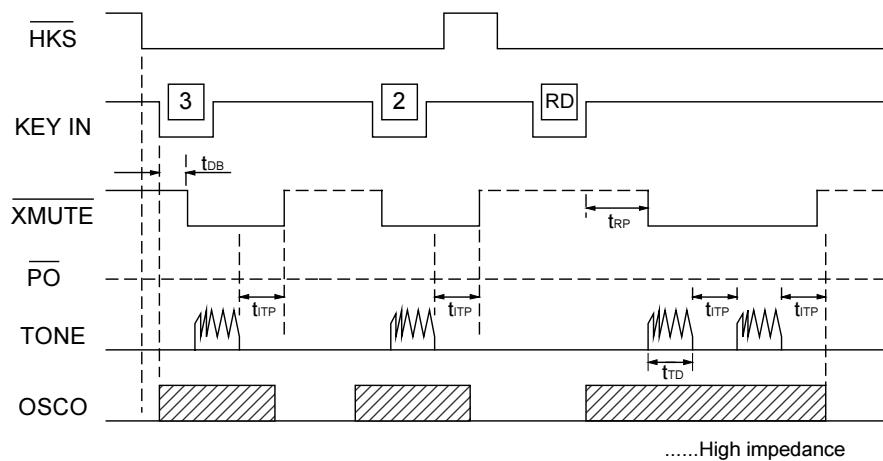
Timing Waveform for mixed dialing Operation
(by MODE pin entry)



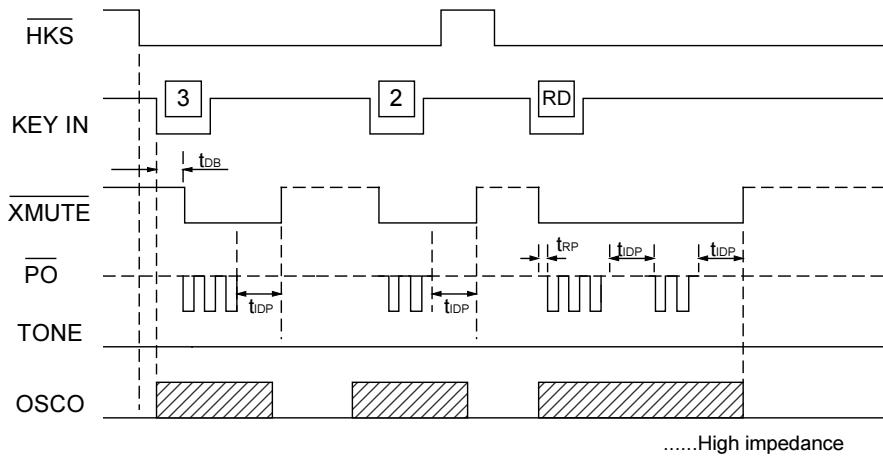
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TIMING DIAGRAMS(continued)



Tone Mode Redial Timming Diagram



Pulse Mode Redial Timming Diagram

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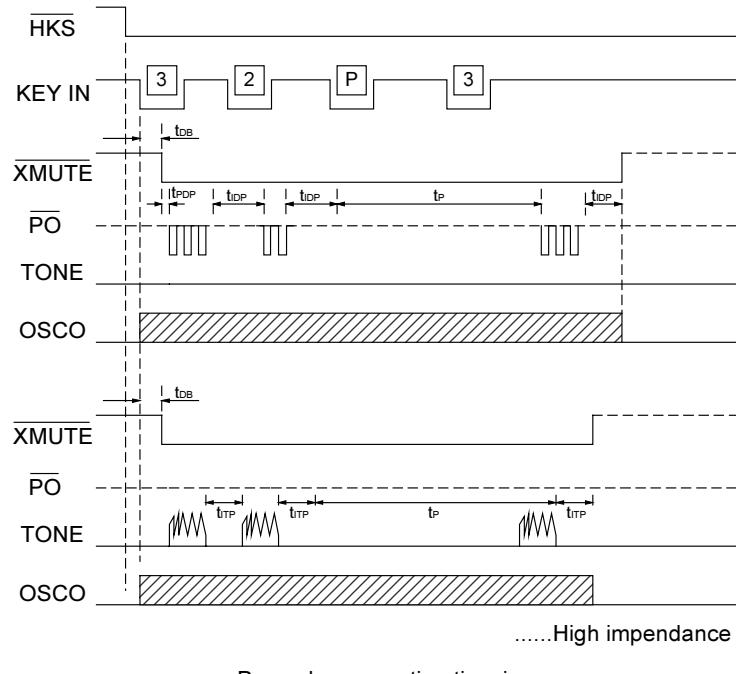
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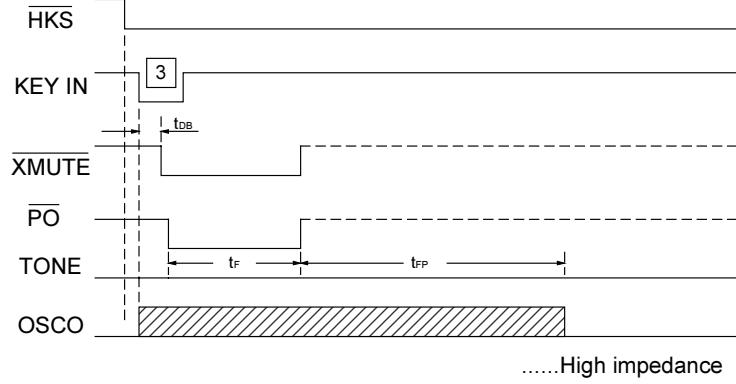
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TIMING DIAGRAMS(continued)



Pause key operating timming



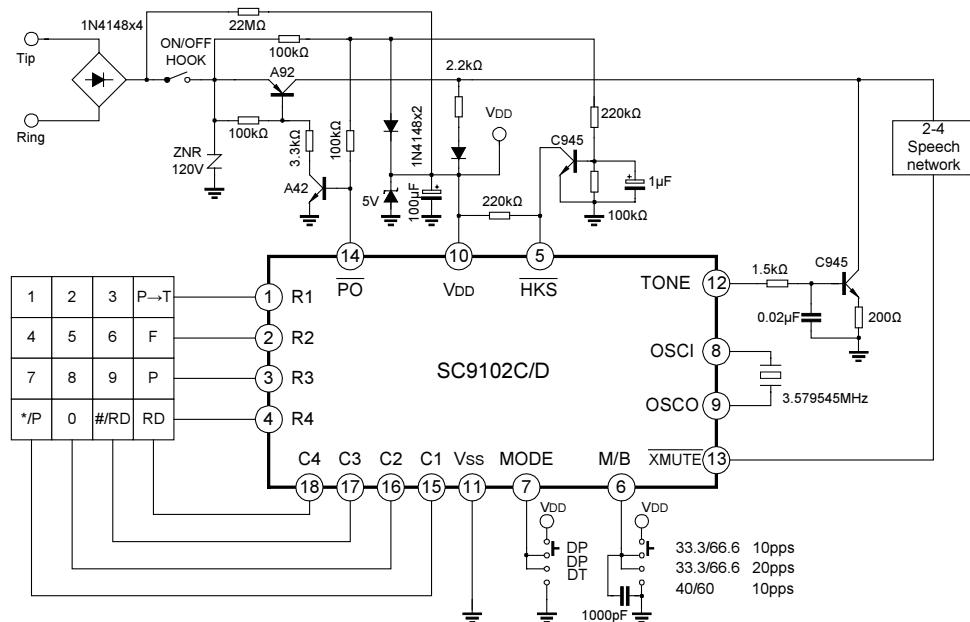
Flash key operating timming



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TYPICAL APPLICATION CIRCUIT



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CHIP TOPOGRAPHY



Chip size: 1.35 x 1.33 mm²

PAD COORDINATES (Unit: μm)

Pad No.	Symbol	X	Y	Pad No.	Symbol	X	Y
1	P1	-545.0	276.0	10	P10	542.2	176.4
2	P2	-545.0	109.0	11	P11	541.3	349.5
3	P3	-539.0	-266.0	12	P12	541.0	530.5
4	P4	539.0	-453.5	13	P13	324.3	531.5
5	P5	21.2	-528.0	14	P14	131.0	533.0
6	P6	191.0	-528.0	15	P15	-27.0	531.5
7	P7	362.5	-381.5	16	P16	-199.5	531.5
8	P8	529.5	8.5	17	P17	-373.0	531.5
9	P9	540.5	176.4	18	P18	-545.0	463.5

Note: The original point of the coordinate is the die center.

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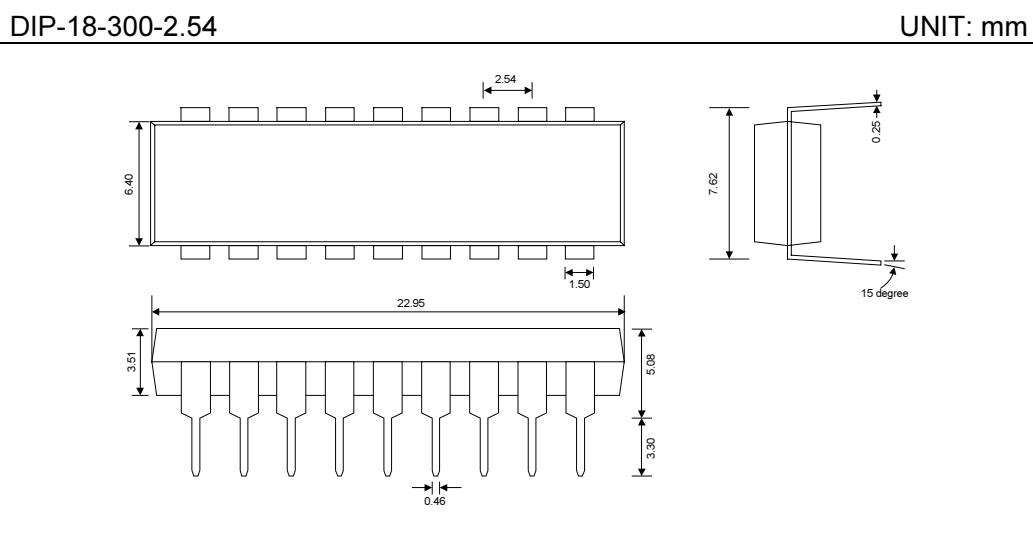
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PACKAGE OUTLINE



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